

TECHNICAL DATA DATA SHEET 4649, REV. A.1

HERMETIC SCHOTTKY RECTIFIER Very Low Forward Voltage Drop

Features:

- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

Maximum Ratings

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	15	V
Max. Average Forward Current	$I_{F(AV)}$	I _{F(AV)} 50% duty cycle, rectangular wave form (Single)		Α
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle, rectangular wave form (Common Cathode)	6	Α
Max. Peak One Cycle Non- Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine wave (per leg)	55	Α
Non-Repetitive Avalanche Energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, \ I_{AS} = 3.0 \text{A}, \ L = 4.4 \text{mH (per leg)}$	20	mJ
Repetitive Avalanche Current	I _{AR}	I_{AS} decay linearly to 0 in 1 μs f limited by T_J max V_A =1.5 V_R	3.0	А
Maximum Thermal Resistance	$R_{ ext{ hetaJC}}$	(per leg)	11.30	°C/W
Max. Junction Temperature	TJ	-	-65 to +175	°C
Max. Storage Temperature	T_{stg}	65 to +17		°C

Electrical Characteristics

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	V _{F1} @ 3.0A, Pulse, T _J = 25 °C		V
(per leg)	V _{F2}	@ 3.0A, Pulse, T _J = 125 °C	0.38	V
Max. Reverse Current	I _{R1}	@V _R = 15V, Pulse,	1.5	mA
		T _J = 25 °C		
(per leg)	I _{R2}	$@V_R = 15V$, Pulse,	70	mA
		T _J = 125 °C		
Max. Junction Capacitance	C _T	$@V_R = 5V, T_C = 25 ^{\circ}C$	240	pF
(per leg)		$f_{SIG} = 1MHz,$		
		$V_{SIG} = 50 \text{mV (p-p)}$		



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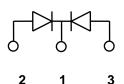
SINGLE

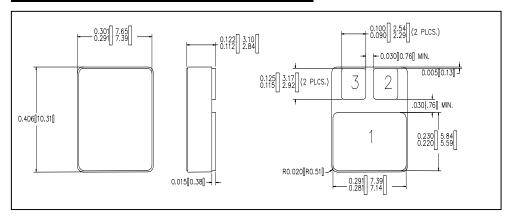
Mechanical Dimensions: in Inches / mm





COMMON CATHODE





PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
COMMON CATHODE - P	COMMON CATHODE	ANODE 1	ANODE 2

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